

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S94	1	"10/798959"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:00
S95	15062	(metal adj insulat\$3 adj metal) 'MIM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:09
S96	1971	capacitor same ONO	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:11
S97	174568	(protect\$4 'SRO' silicon adj rich adj oxide) near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/30 12:10
S98	185039	(protect\$4 'SRO' silicon adj rich adj oxide) near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:13
S99	2785	capacitor same S98	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:11
S100	1641	capacitor with S98	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:14
S101	44	S95 same S100	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:14
S102	184854	(protect\$4 silicon adj rich adj oxide) near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:15

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S10 3	701382	capacitor with10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:15
S10 4	3965	S95 same S103	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:14
S10 5	231	(silicon adj rich adj oxide) near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 10:47
S10 6	701338	capacitor with13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:16
S10 7	3	capacitor with S105	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:16
S10 8	1	S95 with S105	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:16
S10 9	2	S95 same S105	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:16
S11 1	752	(silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:17
S11 2	14	S95 and S111	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 12:17
S11 3	15062	(metal adj insulat\$3 adj metal) 'MIM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 10:34

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S11 4	231	(silicon adj rich adj oxide) near layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:05
S11 5	2	S113 and S114	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 16:55
S11 6	752	(silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:05
S11 7	14	S113 and S116	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:05
S11 8	2270299	(protect\$4 'SRO' silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:08
S11 9	4484	S113 and S118	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:07
S12 0	159160	(protect\$4 'SRO' silicon adj rich adj oxide) adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:10
S12 1	662	S113 and S120	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:09
S12 2	345	('SRO' silicon adj rich adj oxide) adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:11
S12 3	7	S113 and S122	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:10

## EAST Search History

S12 4	15591	('SRO' silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:11
S12 5	122	S113 and S124	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:33
S12 6	214	S116 and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/30 17:33
S12 7	1410	(257/301).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/30 21:54
S12 8	3	S127 and S116	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/30 21:54
S12 9	816	257/E21.545,E21.652,E27.096.ccls.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/11/30 22:08
S13 0	2886	257/E21.009,E21.021.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/11/30 22:42
S13 1	6545	(257/296,303,304,306,307,308).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 05:53
S13 2	10734	S131 and (metal adj insulat\$3 adj metal) 'MIM'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 08:59
S13 3	9	S132 and (silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 09:51

## EAST Search History

S13 4	6550	S131 andcapacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 08:47
S13 5	6551	S131 andcapacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 08:47
S13 6	13	S135 and (silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 08:48
S13 7	1	((((metal adj insulat\$3 adj metal) 'MIM') near capacitor) and bottom near3 electrode and (SRO "silicon on insulator" silicon adj on adj insulator) and silicon near content.clm.	US-PGPUB	OR	OFF	2006/12/01 11:07
S13 8	4643	257/532,529-535.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 09:28
S13 9	2099	257/532.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 09:29
S14 0	1814	S139 and @ad<"20040310"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 09:32
S14 1	8	S138 and (silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 10:01
S14 2	155	438/957.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 10:01
S14 3	1157	438/52,53.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 10:46

## EAST Search History

S14 4	6	S143 and ((metal adj insulat\$3 adj metal) 'MIM')	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 10:37
S14 5	1637	"438"/\$.ccls. and ((metal adj insulat\$3 adj metal) 'MIM' metal adj in adj metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 10:38
S14 6	6	S143 and ((metal adj insulat\$3 adj metal) 'MIM' metal adj in adj metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 10:38
S14 7	1146	438/239.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/01 10:47
S14 8	5	S147 and (silicon adj rich adj oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/01 10:47

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	1	((((metal adj insulat\$3 adj metal) 'MIM')) and bottom near3 electrode and (SRO "silicon on insulator" silicon adj on adj insulator) and silicon near content.clm.	US-PGPUB	OR	ON	2006/12/01 11:08